XC6223 Series

ETR0339-010

Built-in Inrush Current Protection, 300mA High Speed LDO Voltage Regulator

■GENERAL DESCRIPTION

The XC6223 series is a high speed LDO regulator that features high accurate, low noise, high ripple rejection, low dropout and low power consumption. The series consists of a voltage reference, an error amplifier, a driver transistor, a current limiter, a phase compensation circuit, a thermal shutdown circuit and an inrush current protection circuit.

The CE function enables the circuit to be in stand-by mode by inputting low level signal. In the stand-by mode, the series enables the electric charge at the output capacitor C_L to be discharged via the internal switch, and as a result the V_{OUT} pin quickly returns to the V_{SS} level. The output stabilization capacitor C_L is also compatible with low ESR ceramic capacitors.

The output voltage is selectable in 0.05V increments within the range of 1.2V to 4.0V which fixed by laser trimming technologies. The over current protection circuit and the thermal shutdown circuit are built-in. These two protection circuits will operate when the output current reaches current limit level or the junction temperature reaches temperature limit level.
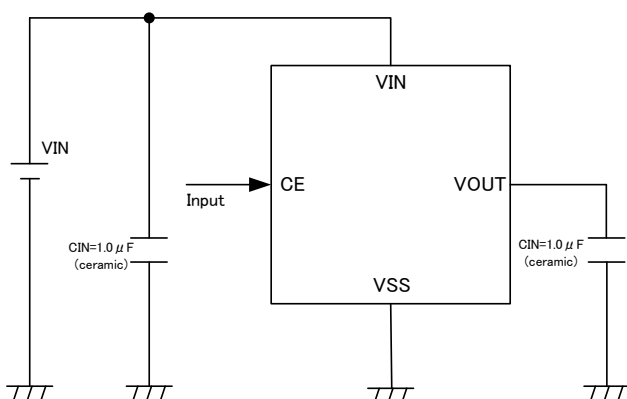
■APPLICATIONS

- ●Digital still cameras
- ●Smart phones / Mobile phones
- ●Portable game consoles
- ●Modules (wireless, cameras, etc.)
- ●IC recorders
- ●Mobile devices / terminals
- ●Bluetooth
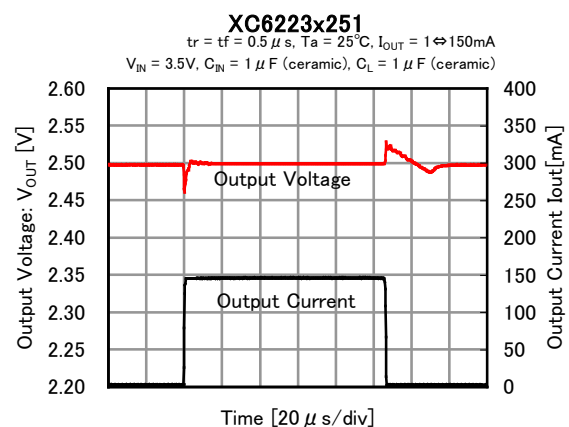- ●Wireless LAN
- ●Digital TV tuners

■FEATURES

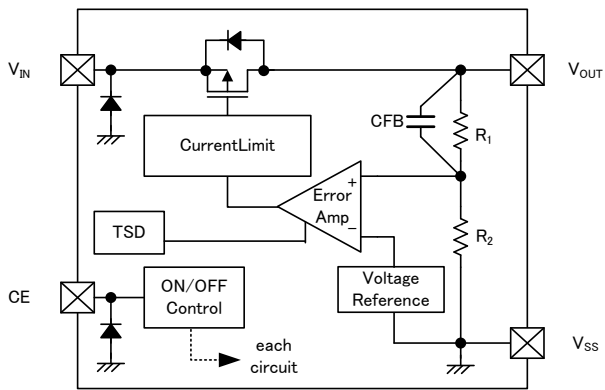|	
Maximum Output Current	: 300mA
Input Voltage Range	: 1.6 ~ 5.5V
Output Voltages	: 2.0 ~ 4.0V (Accuracy ±1%)
	1.2 ~ 1.95V (Accuracy ±20mV)
	0.05V increments
Dropout Voltage	: 200mV@I_{OUT}=300mA (V_{OUT}=3.0V)
Low Power Consumption	: 100µA
Stand-by Current	: 0.1µA
High Ripple Rejection	: 80dB@f=1kHz
Protection Circuits	: Current Limit (400mA)
	Short Circuit Protection
	Over Heat Protection
	Inrush Current Protection
Low ESR Capacitors	: C_{IN} =1.0µF, C_L=1.0µF
CE Function	: Active High
	C_L High Speed Discharge
Operating Ambient Temperature	: -40℃~ +105℃
Packages	: USPQ-4B03
	USP-4
	SSOT-24
	SOT-25
	SOT-89-5
Environmentally Friendly	: EU RoHS Compliant, Pb Free

■TYPICAL APPLICATION CIRCUIT

■ TYPICAL PERFORMANCE CHARACTERISTICS

XC6223x251
tr = tf = 0.5µs, Ta = 25℃, I_{OUT} = 1⇔150mA
V_{IN} = 3.5V, C_{IN} = 1µF (ceramic), C_L = 1µF (ceramic)

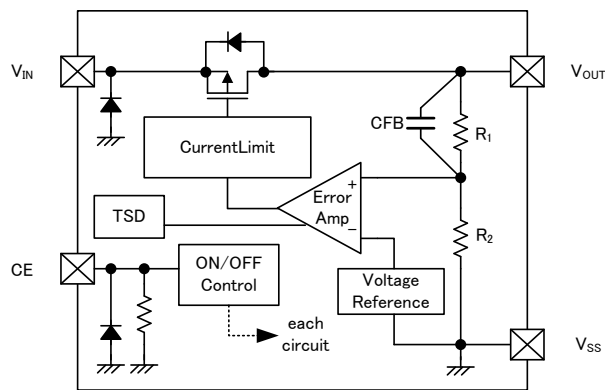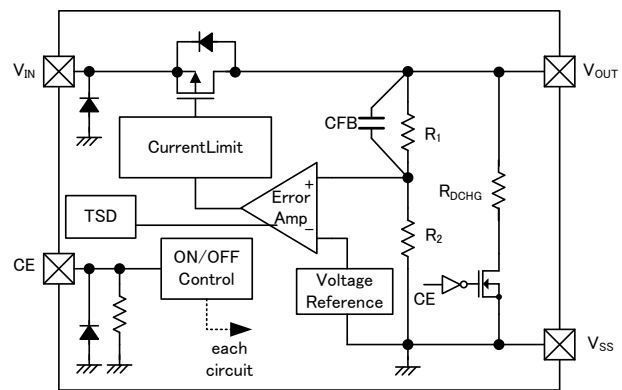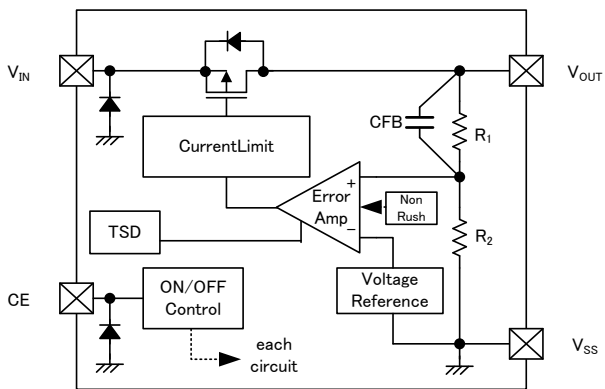## ■BLOCK DIAGRAMS

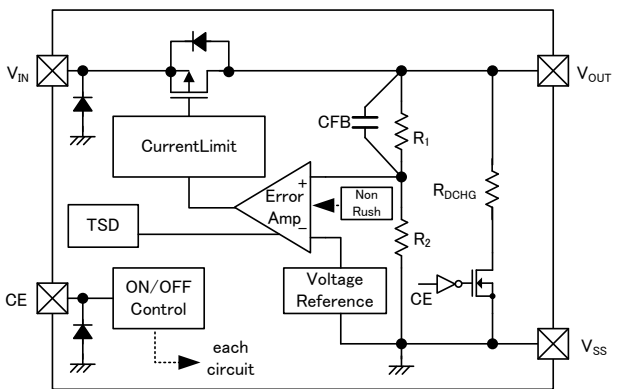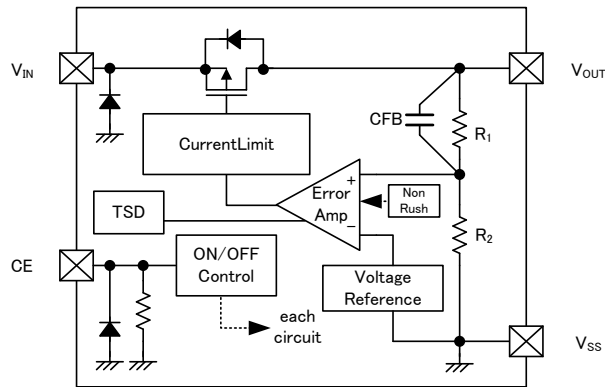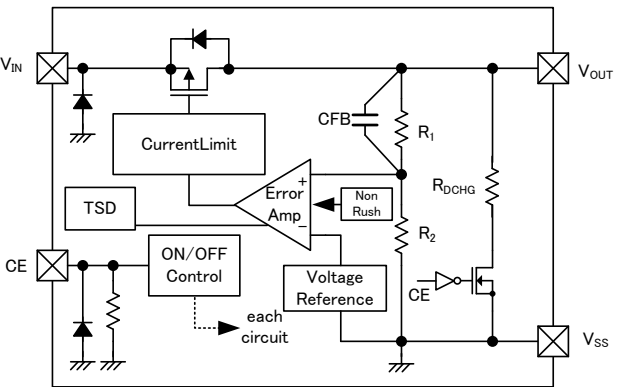XC6223A Series
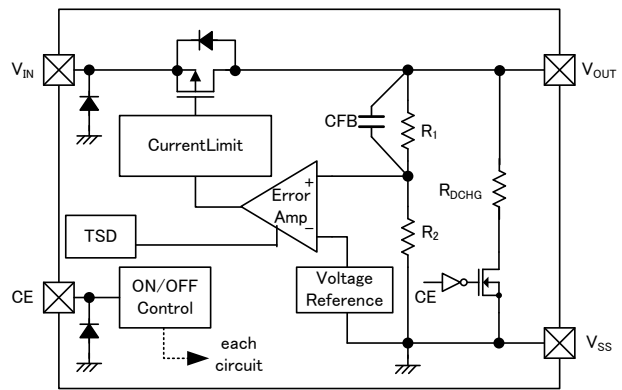
XC6223B Series

XC6223C Series

XC6223D Series

XC6223E Series

XC6223F Series

XC6223G Series

XC6223H Series

* Diodes inside the circuits are ESD protection diodes and parasitic diodes

■PRODUCT CLASSIFICATION

●Ordering Information

XC6223①②③④⑤⑥-⑦(*1)

DESIGNATOR	ITEM	SYMBOL	DESCRIPTION
①	Type of Regulator	A/J(*3)	Without Inrush Current Protection, Without CE Pull-down, Without C_L discharge (Semi-Custom)
		B/K(*3)	Without Inrush Current Protection, Without CE Pull-down, With C_L discharge (Semi-Custom)
		C/M(*3)	Without Inrush Current Protection, With CE Pull-down(*2), Without C_L discharge (Semi-Custom)
		D/N(*3)	Without Inrush Current Protection, With CE Pull-down(*2), With C_L discharge
		E/P(*3)	With Inrush Current Protection, Without CE Pull-down, Without CL discharge (Semi-Custom)
		F/Q(*3)	With Inrush Current Protection, Without CE Pull-down, With C_L discharge (Semi-Custom)
		G/R(*3)	With Inrush Current Protection, With CE Pull-down(*2), Without C_L discharge (Semi-Custom)
		H/T(*3)	With Inrush Current Protection, With CE Pull-down(*2), With C_L discharge
②③	Output Voltage	12~40	ex.) 2.80V → ②=2, ③=8, ④=please see down below.
④	Output Accuracy	1	±1% (V_{OUT}≧2.0V) ±0.02V (V_{OUT}<2.0V) In case of 2nd decimal place 0 (ex.2.80V → ④=1)
		B	±1% (V_{OUT}≧2.0V) ±0.02V (V_{OUT}<2.0V) In case of 2nd decimal place 5 (ex.2.85V → ④=B)
⑤⑥-⑦(*1)	Packages (Order Unit)	9R-G	USPQ-4B03 (5,000pcs/Reel)
		GR-G	USP-4 (3,000pcs/Reel)
		NR-G	SSOT-24 (3000pcs/Reel)
		MR-G	SOT-25 (3,000pcs/Reel)
		PR-G	SOT-89-5 (1,000pcs/Reel)

(*1) The "-G" suffix denotes Halogen and Antimony free as well as being fully EU RoHS compliant.
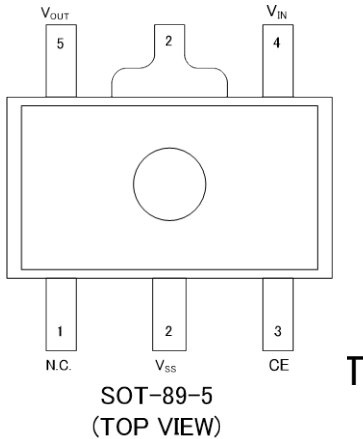
(*2) With CE pin pull-down resistor.

(*3) Product types A/B/C/D/E/F/G/H are for pre-existing customers who were or are already using these types of products. For customers who intend to adopt this product newly, please select from types J/K/M/N/P/Q/R/T which have been extended the operating temperature range (105°Ccompliance).

■PIN CONFIGURATION

SOT-89-5
(TOP VIEW)
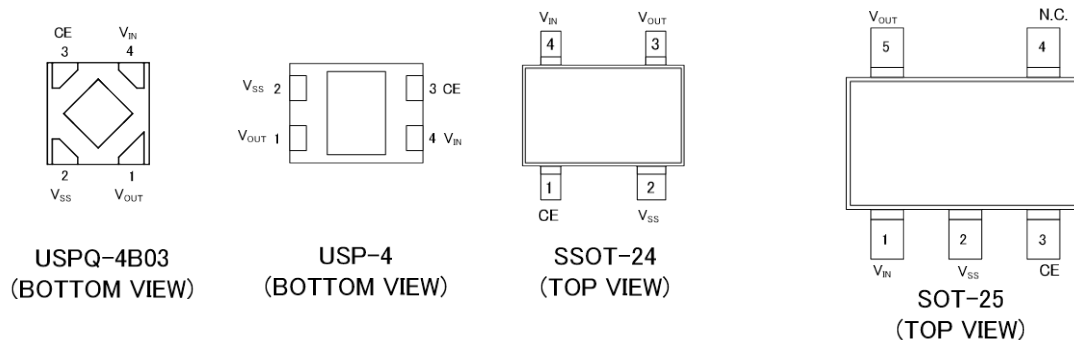
*The dissipation pad for the USPQ-4B03,USP-4 packages should be solder-plated in reference mount pattern and metal masking so as to enhance mounting strength and heat release.   If the pad needs to be connected to other pins, it should be connected to the V_{SS} (No. 2) pin.

PIN NUMBER					PIN NAME	FUNCTIONS
USPQ-4B03	USP-4	SSOT-24	SOT-25	SOT-89-5		
4	4	4	1	4	V_{IN}	Power Input
1	1	3	5	5	V_{OUT}	Output
2	2	2	2	2	V_{SS}	Ground
3	3	1	3	3	CE	ON/OFF Control
-	-	-	4	1	NC	No Connection

■PIN FUNCTION ASSIGNMENT
■LOGIC CONDITION FOR THE PIN

PIN NAME	DESIGNATOR	CONDITION
CE	L	$0V \leqq V_{CE} \leqq 0.3V$
	H	$1.0V \leqq V_{CE} \leqq 5.5V$
	OPEN	CE=OPEN

CE LOGIC CONDITION	IC OPERATION
H	Operation ON
L	Operation OFF(Stand-by)
OPEN	*

* Undefined state in XC6223 A/B/E/F/J/K/P/Q. On the other hand, Operation OFF states in XC6223C/D/G/H/M/N/R/T because that an internal pull-down resister maintains the CE pin voltage to be low.

■ABSOLUTE MAXIMUM RATINGS

●XC6223A/B/C/D/E/F/G/H Series

Ta=25℃

PARAMETER		SYMBOL	RATINGS	UNITS
Input Voltage		V_{IN}	V_{SS}-0.3 ~ +7.0	V
Output Current		I_{OUT}	500 [*1]	mA
Output Voltage		V_{OUT}	V_{SS}-0.3 ~ V_{IN}+0.3	V
CE Input Voltage		V_{CE}	V_{SS}-0.3 ~ +7.0	V
Power Dissipation	USPQ-4B03	Pd	100	mW
			550 (40mm x 40mm Standard board) [*2]	
	USP-4		120	
			1000 (40mm x 40mm Standard board) [*2]	
	SSOT-24		150	
			500 (40mm x 40mm Standard board) [*2]	
			680(JESD51-7 board) [*2]	
	SOT-25		250	
			600 (40mm x 40mm Standard board) [*2]	
			760(JESD51-7 board) [*2]	
	SOT-89-5		500	
			1300 (40mm x 40mm Standard board) [*2]	
			1750(JESD51-7 board) [*2]	
Operating Ambient Temperature		Topr	-40 ~ +85	℃
Storage Temperature		Tstg	-55 ~ +125	℃

[*1] $I_{OUT} \leqq Pd / (V_{IN}-V_{OUT})$

[*2] The power dissipation figure shown is PCB mounted and is for reference only.

The mounting condition is please refer to PACKAGING INFORMATION.

●XC6223J/K/M/N/P/Q/R/T Series

Ta=25℃

PARAMETER		SYMBOL	RATINGS	UNITS
Input Voltage		V_{IN}	V_{SS}-0.3 ~ +7.0	V
Output Current		I_{OUT}	500 [*1]	mA
Output Voltage		V_{OUT}	V_{SS}-0.3 ~ V_{IN}+0.3	V
CE Input Voltage		V_{CE}	V_{SS}-0.3 ~ +7.0	V
Power Dissipation	USPQ-4B03	Pd	100	mW
			550 (40mm x 40mm Standard board) [*2]	
	USP-4		120	
			1000 (40mm x 40mm Standard board) [*2]	
	SSOT-24		150	
			500 (40mm x 40mm Standard board) [*2]	
			680(JESD51-7 board) [*2]	
	SOT-25		250	
			600 (40mm x 40mm Standard board) [*2]	
			760(JESD51-7 board) [*2]	
	SOT-89-5		500	
			1300 (40mm x 40mm Standard board) [*2]	
			1750(JESD51-7 board) [*2]	
Operating Ambient Temperature		Topr	-40 ~ +105	℃
Storage Temperature		Tstg	-55 ~ +125	℃

[*1] $I_{OUT} \leqq Pd / (V_{IN}-V_{OUT})$

[*2] The power dissipation figure shown is PCB mounted and is for reference only.

The mounting condition is please refer to PACKAGING INFORMATION.

■ELECTRICAL CHARACTERISTICS

● XC6223A/B/C/D/E/F/G/H/J/K/M/N/P/Q/R/T Series

Ta=25℃

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS	CIRCUITS
Output Voltage	$V_{OUT(E)}$ (*1)	$V_{OUT(T)} \geqq 2.0V$, $V_{CE}=V_{IN}$, $I_{OUT}=10mA$	$V_{OUT(T)} \times 0.99$ (*2)	$V_{OUT(T)}$ (*2)	$V_{OUT(T)} \times 1.01$ (*2)	V	①
		$V_{OUT(T)}<2.0V$, $V_{CE}=V_{IN}$, $I_{OUT}=10mA$ (*3)	$V_{OUT(T)}-20mV$ (*2)	$V_{OUT(T)}$ (*2)	$V_{OUT(T)}+20mV$ (*2)	V	
Maximum Output Current	I_{OUTMAX}	$V_{CE}=V_{IN}$	300	-	-	mA	①
Load Regulation	ΔV_{OUT}	$V_{CE}=V_{IN}$, $0.1mA \leqq I_{OUT} \leqq 300mA$	-	25	45	mV	①
Dropout Voltage	Vdif (*4)	$V_{CE}=V_{IN}$, $I_{OUT}=300mA$		E-1		mV	①
Supply Current	I_{SS}	$V_{CE}=V_{IN}$	-	100	220	μA	②
Stand-by Current	I_{STB}	$V_{CE}=V_{SS}$	-	0.01	0.4	μA	②
Line Regulation	$\Delta V_{OUT}/(\Delta V_{IN} \cdot V_{OUT})$	$V_{OUT(T)}+0.5V \leqq V_{IN} \leqq 5.5V$ $V_{CE}=V_{IN}$, $I_{OUT}=50mA$	-	0.01	0.1	%/V	①
Input Voltage	V_{IN}	-	1.6	-	5.5	V	①
Output Voltage Temperature Characteristics (A/B/C/D/E/F/G/H Type)	$\Delta V_{OUT}/(\Delta Ta \cdot V_{OUT})$	$V_{CE}=V_{IN}$, $I_{OUT}=10mA$ $-40℃ \leqq Ta \leqq 85℃$	-	±100	-	ppm / ℃	①
Output Voltage Temperature Characteristics (J/K/M/N/P/Q/R/T Type)	$\Delta V_{OUT}/(\Delta Ta \cdot V_{OUT})$	$V_{CE}=V_{IN}$, $I_{OUT}=10mA$ $-40℃ \leqq Ta \leqq 105℃$	-	±100	-	ppm / ℃	①
Power Supply Rejection Ratio	PSRR	$V_{OUT(T)}<2.5V$ $V_{IN}=3.0V_{DC}+0.5Vp-p_{AC}$ $V_{CE}=V_{OUT(T)}+1.0V$ $I_{OUT}=30mA$、f=1kHz	-	80	-	dB	③
		$V_{OUT(T)} \geqq 2.5V$ $V_{IN}=\{V_{OUT(T)}+1.0\}V_{DC}+0.5Vp-p_{AC}$ $V_{CE}=V_{OUT(T)}+1.0V$ $I_{OUT}=30mA$、f=1kHz					
Current Limit	I_{LIM}	$V_{CE}=V_{IN}$	310	400	-	mA	①
Short Current	I_{SHORT}	$V_{CE}=V_{IN}$, $V_{OUT}=V_{SS}$	-	50	-	mA	①
CE High Level Voltage	V_{CEH}	-	1.0	-	5.5	V	④
CE Low Level Voltage	V_{CEL}	-	-	-	0.3	V	④
CE High Level Current (A/B/E/F/J/K/P/Q Type)	I_{CEH}	$V_{CE}=V_{IN}=5.5V$	-0.1	-	0.1	μA	④
CE High Level Current (C/D/G/H/M/N/R/T Type)	I_{CEH}	$V_{CE}=V_{IN}=5.5V$	3.0	5.5	9.0	μA	④
CE Low Level Current	I_{CEL}	$V_{CE}=V_{SS}$	-0.1	-	0.1	μA	④
C_L Discharge Resistance (Only B/D/F/H/K/N/Q/T Type)	R_{DCHG}	$V_{IN}=5.5V$, $V_{OUT}=2.0V$, $V_{CE}=V_{SS}$	-	300	-	Ω	①
Inrush Current (Only E/F/G/H/P/Q/R/T Type)	Irush	$V_{IN}=V_{CE}=5.5V$	-	150	-	mA	⑤
Thermal Shutdown Detect Temperature	T_{TSD}	Junction Temperature	-	150	-	℃	
Thermal Shutdown Release Temperature	T_{TSR}	Junction Temperature	-	120	-	℃	①
Thermal Shutdown Hysteresis Width	$T_{TSD} - T_{TSR}$	Junction Temperature	-	30	-	℃	

NOTE:
(*1)$V_{OUT(E)}$: Effective output voltage
        (i.e. the output voltage when "$V_{OUT(T)}+1.0V$" is provided at the V_{IN} pin while maintaining a certain I_{OUT} value.)
(*2)$V_{OUT(T)}$: Nominal output voltage
(*3)The standard output voltage is specified in $V_{OUT(T)} \pm 20mV$ where $V_{OUT(T)}<2.0V$.
(*4)Vdif=$\{V_{IN1}\{*5\}-V_{OUT1}\{*6\}\}$ ($V_{IN1} \geqq 1.6V$)
(*5)V_{IN1}=The input voltage when V_{OUT1} appears as input voltage is gradually decreased.
(*6)V_{OUT1}=A voltage equal to 98% of the output voltage whenever an amply stabilized I_{OUT} $\{V_{OUT(T)}+1.0V\}$ is input
(*7) Unless otherwise stated regarding input voltage conditions, $V_{IN}=V_{OUT(T)}+1.0V$.

■ELECTRICAL CHARACTERISTICS (Continued)

● Voltage Chart 1

SYMBOL	E-0		E-1	
PARAMETER / NOMINAL OUTPUT VOLTAGE (V)	OUTPUT VOLTAGE (V)		DROPOUT VOLTAGE (mV)	
	$V_{OUT(E)}$		Vdif	
$V_{OUT(T)}$	MIN	MAX	TYP	MAX
1.20	1.1800	1.2200	480	630
1.25	1.2300	1.2700		
1.30	1.2800	1.3200	440	580
1.35	1.3300	1.3700		
1.40	1.3800	1.4200	420	520
1.45	1.4300	1.4700		
1.50	1.4800	1.5200		
1.55	1.5300	1.5700		
1.60	1.5800	1.6200	400	440
1.65	1.6300	1.6700		
1.70	1.6800	1.7200		
1.75	1.7300	1.7700		
1.80	1.7800	1.8200	300	410
1.85	1.8300	1.8700		
1.90	1.8800	1.9200		
1.95	1.9300	1.9700		
2.00	1.9800	2.0200	270	380
2.05	2.0295	2.0705		
2.10	2.0790	2.1210		
2.15	2.1285	2.1715		
2.20	2.1780	2.2220		
2.25	2.2275	2.2725		
2.30	2.2770	2.3230		
2.35	2.3265	2.3735		
2.40	2.3760	2.4240		
2.45	2.4255	2.4745		
2.50	2.4750	2.5250	240	350
2.55	2.5245	2.5755		
2.60	2.5740	2.6260		
2.65	2.6235	2.6765		
2.70	2.6730	2.7270		
2.75	2.7225	2.7775		

■ELECTRICAL CHARACTERISTICS (Continued)

● Voltage Chart2

SYMBOL	E-0		E-1	
PARAMETER NOMINAL OUTPUT VOLTAGE (V)	OUTPUT VOLTAGE (V)		DROPOUT VOLTAGE (mV)	
$V_{OUT(T)}$	$V_{OUT(E)}$		Vdif	
	MIN.	MAX.	TYP.	MAX.
2.80	2.7720	2.8280	240	350
2.85	2.8215	2.8785		
2.90	2.8710	2.9290		
2.95	2.9205	2.9795		
3.00	2.9700	3.0300	200	305
3.05	3.0195	3.0805		
3.10	3.0690	3.1310		
3.15	3.1185	3.1815		
3.20	3.1680	3.2320		
3.25	3.2175	3.2825		
3.30	3.2670	3.3330		
3.35	3.3165	3.3835		
3.40	3.3660	3.4340		
3.45	3.4155	3.4845		
3.50	3.4650	3.5350		
3.55	3.5145	3.5855		
3.60	3.5640	3.6360		
3.65	3.6135	3.6865		
3.70	3.6630	3.7370		
3.75	3.7125	3.7875		
3.80	3.7620	3.8380		
3.85	3.8115	3.8885		
3.90	3.8610	3.9390		
3.95	3.9105	3.9895		
4.00	3.9600	4.0400		

■TEST CIRCUITS

● Circuit ①
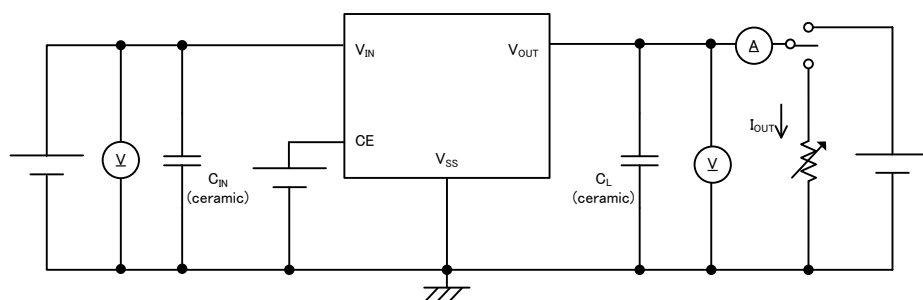
● Circuit ②
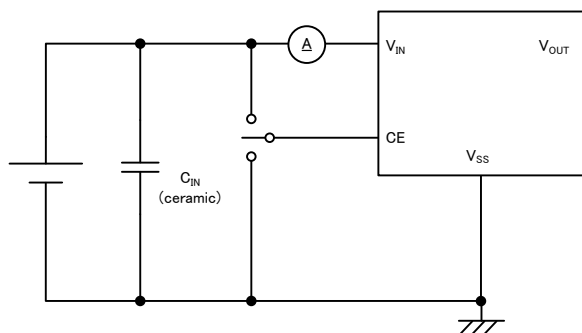
● Circuit ③
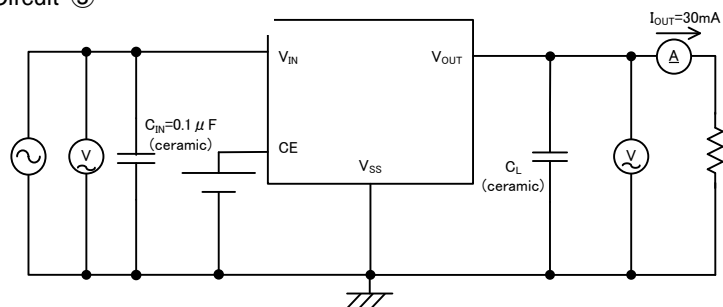
■TEST CIRCUITS (Continued)

●Circuit ④
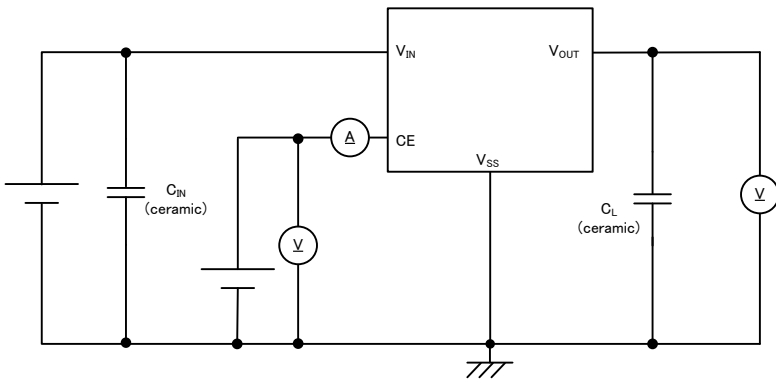
●Circuit ⑤
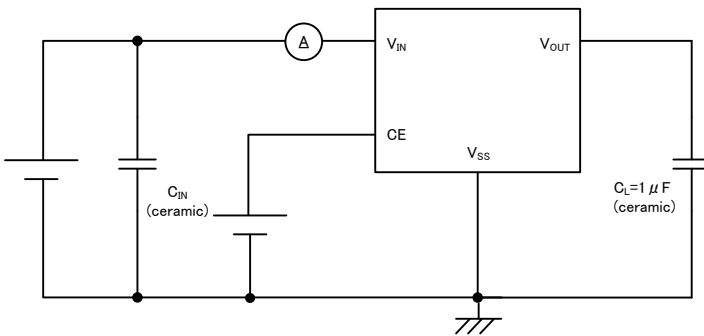
■ OPERATIONAL EXPLANATION
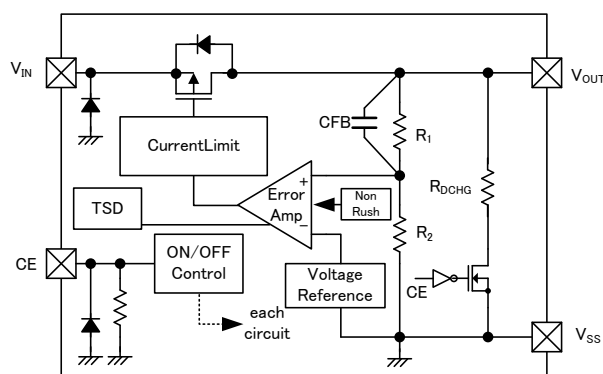
The voltage divided by resistors R1 & R2 is compared with the internal reference voltage by the error amplifier. The P-channel MOSFET which is connected to the Output pin (V_{OUT}) is then driven by the subsequent control signal. The output voltage at the Output pin (V_{OUT}) is controlled and stabilized by a system of negative feedback. The current limit circuit and short circuit protection operate in relation to the level of output current and heat dissipation. Further, the IC's internal circuitry can be shutdown via the CE pin (CE) signal.

<Low ESR Capacitor>

The XC6223 series needs an output capacitor C_L for phase compensation. In order to ensure the stable phase compensation, please place an output capacitor of 1.0μF or bigger at the V_{OUT} pin and V_{SS} pin as close as possible.   For a stable power input, please connect an input capacitor (C_{IN}) of 1.0μF between the input pin (V_{IN}) and the ground pin (V_{SS}).

<Current Limiter, Short-Circuit Protection>

The protection circuit operates as a combination of an output current limiter and fold-back short circuit protection. When load current reaches the current limit level, the output voltage drops. As a result, the load current starts to reduce with showing fold-back curve. The output current finally falls at the level of 50mA when the output pin is short-circuited.

<CE Pin>

The IC's internal circuitry can be shutdown via the signal from the CE pin (CE). In shutdown mode, the XC6223B/D/F/H/K/N/Q/T series enables the electric charge at the output capacitor (C_L) to be discharged via the internal auto-discharge switch, and as a result the output pin (V_{OUT}) quickly returns to the ground pin (V_{SS}) level. When the CE pin (CE) is open, the output voltage becomes undefined state in the XC6223A/B/E/F/J/K/P/Q series because of a high active and no pull-down. On the other hand, the XC6223C/D/G/H/M/N/R/T series has a pull-down resistor at the CE pin (CE) inside, so that the CE pin (CE) input current flows.

<Thermal Shutdown>

When the junction temperature of the built-in driver transistor reaches the temperature limit, the thermal shutdown circuit operates and the driver transistor will be set to OFF. The IC resumes its operation when the thermal shutdown function is released and the IC's operation is automatically restored because the junction temperature drops to the level of the thermal shutdown release voltage.

<Inrush Current Protection>

The inrush current protection circuit is built in the XC6223 series.
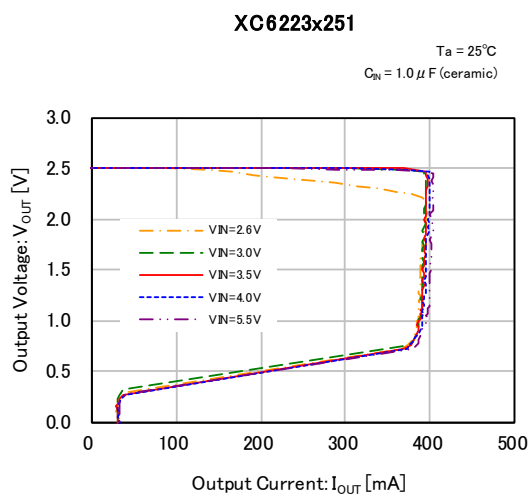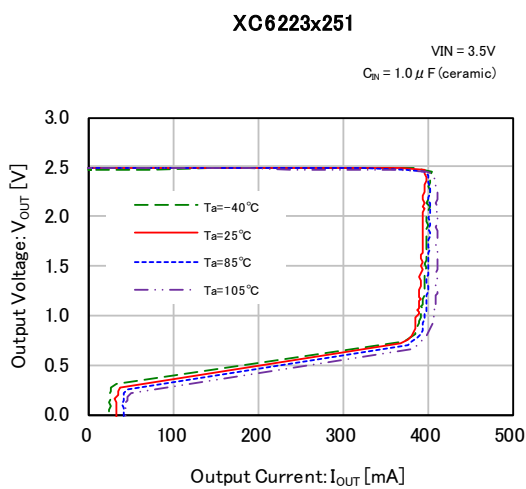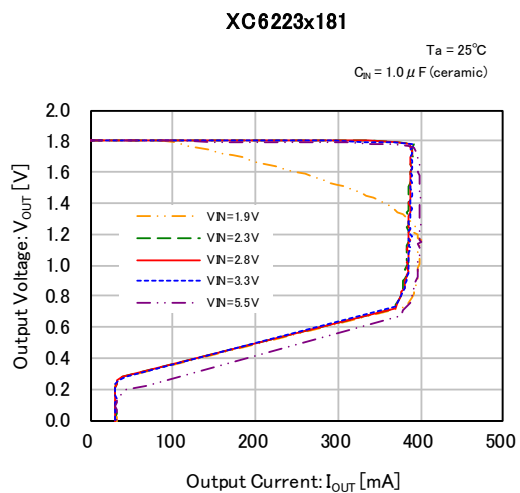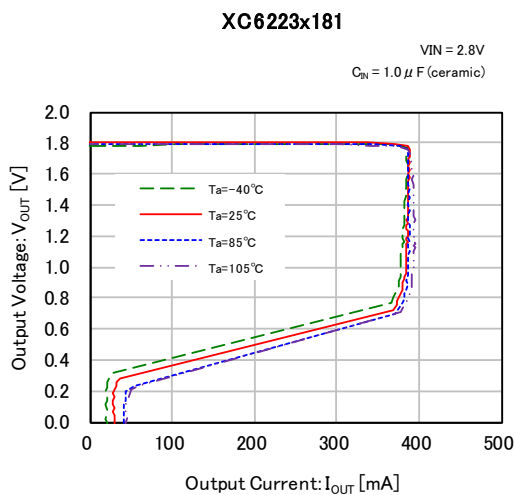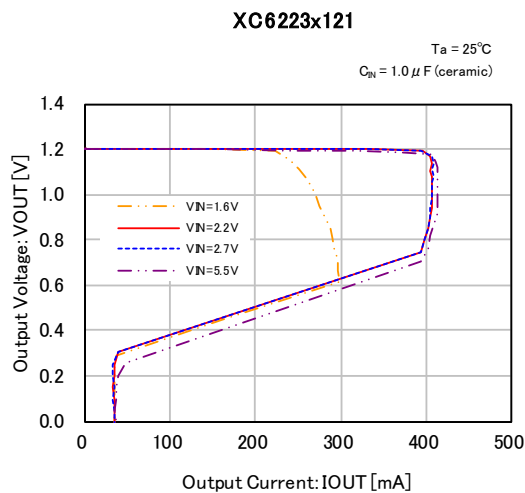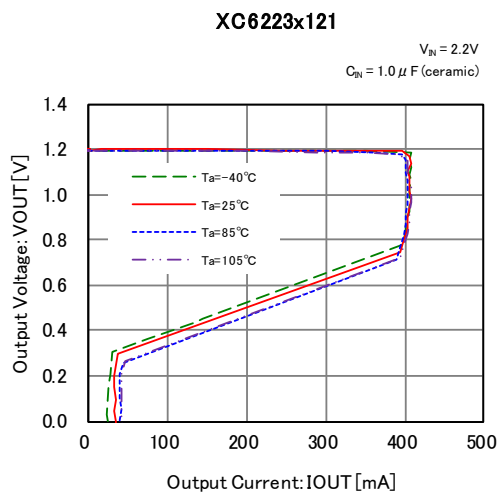
When the IC starts to operate, the protection circuit limits the inrush current from input pin (V_{IN}) to output pin (V_{OUT}) to charge C_L capacitor. This function is built in the XC6223E/F/G/H/P/Q/R/T series.

■ NOTES ON USE

1.   Where wiring impedance is high, operations may become unstable due to the noise and/or phase lag depending on output current.   Please strengthen input pin (V_{IN}) and output pin (V_{OUT}) wiring in particular.

2.   The input capacitor C_{IN} and the output capacitor C_L should be placed to the as close as possible with a shorter wiring.

3.   The IC is controlled with constant current start-up. Start-up sequence control is requested to draw a load current after even nominal output voltage rising up the output voltage.

4.   For temporary, transitional voltage drop or voltage rising phenomenon, the IC is liable to malfunction should the ratings be exceeded.

5.   Torex places an importance on improving our products and its reliability.
     However, by any possibility, we would request user fail-safe design and post-aging treatment on system or equipment.
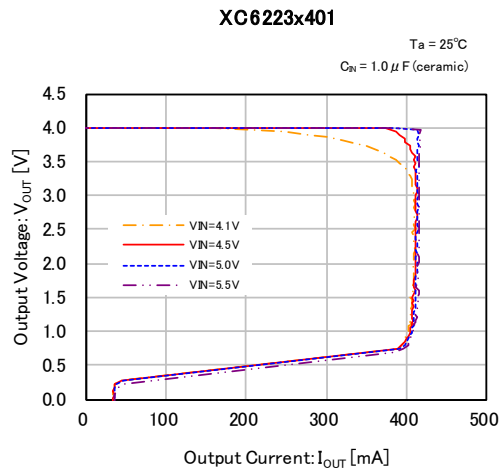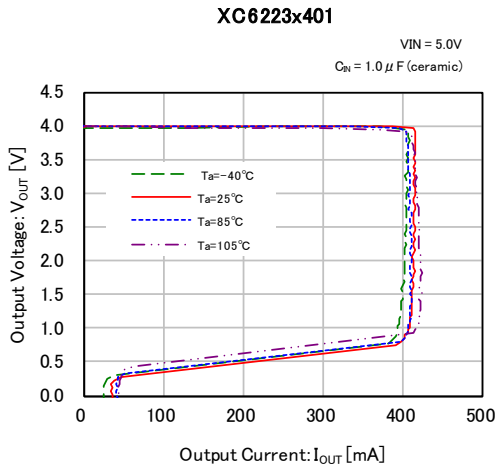
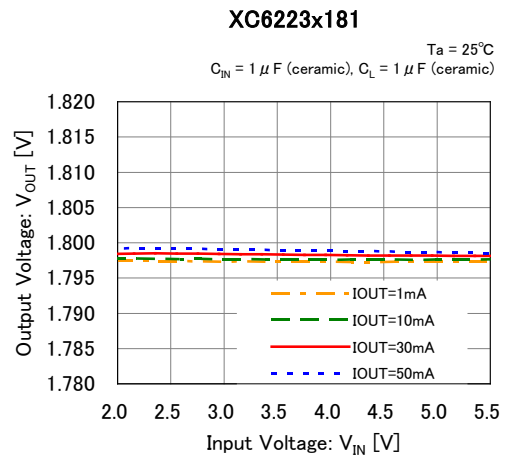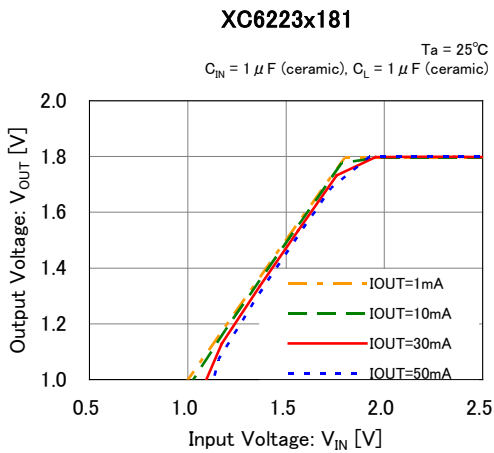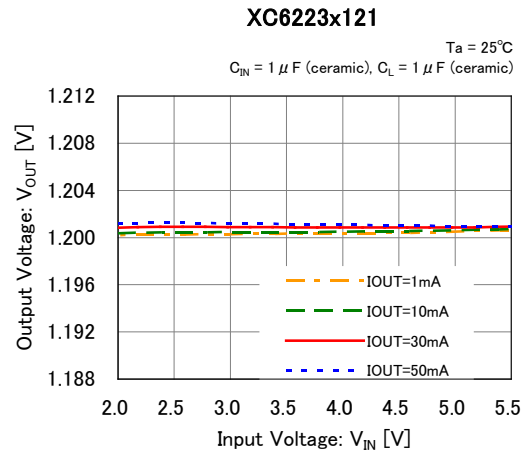# ■TYPICAL PERFORMANCE CHARACTERISTICS
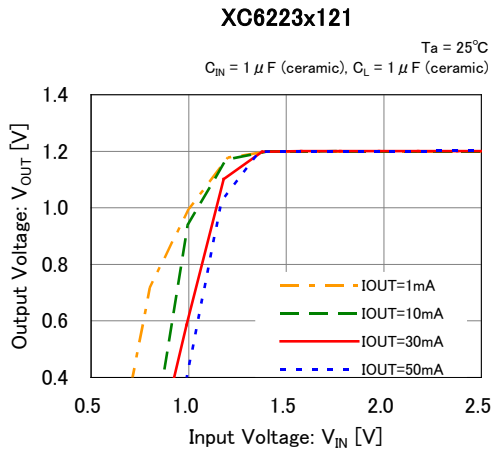
(1) Output Voltage vs. Output Current

XC6223x121

V_{IN} = 2.2V
C_{IN} = 1.0 μF (ceramic)

Legend: Ta=-40℃, Ta=25℃, Ta=85℃, Ta=105℃

XC6223x121

Ta = 25℃
C_{IN} = 1.0 μF (ceramic)

Legend: VIN=1.6V, VIN=2.2V, VIN=2.7V, VIN=5.5V

XC6223x181

VIN = 2.8V
C_{IN} = 1.0 μF (ceramic)

Legend: Ta=-40℃, Ta=25℃, Ta=85℃, Ta=105℃

XC6223x181

Ta = 25℃
C_{IN} = 1.0 μF (ceramic)

Legend: VIN=1.9V, VIN=2.3V, VIN=2.8V, VIN=3.3V, VIN=5.5V

XC6223x251

VIN = 3.5V
C_{IN} = 1.0 μF (ceramic)

Legend: Ta=-40℃, Ta=25℃, Ta=85℃, Ta=105℃

XC6223x251

Ta = 25℃
C_{IN} = 1.0 μF (ceramic)

Legend: VIN=2.6V, VIN=3.0V, VIN=3.5V, VIN=4.0V, VIN=5.5V

■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(1) Output Voltage vs. Output Current (Continued)

XC6223x401

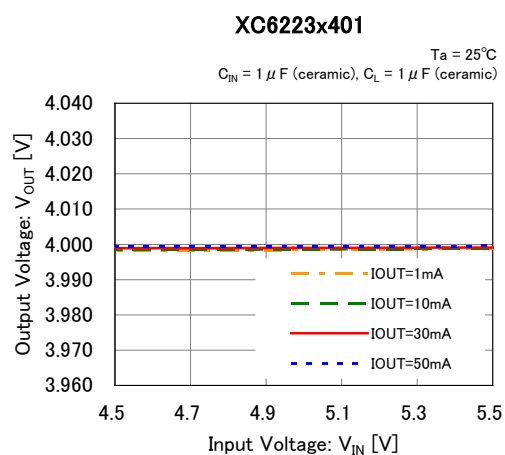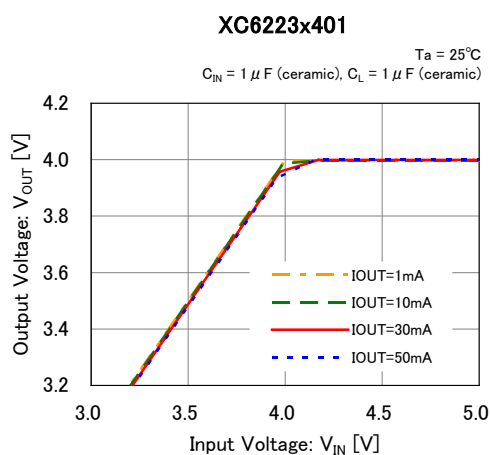VIN = 5.0V
$C_{IN} = 1.0 \mu F$ (ceramic)
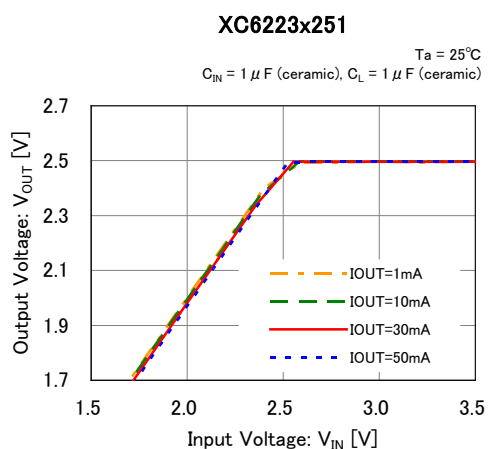

XC6223x401

Ta = 25℃
$C_{IN} = 1.0 \mu F$ (ceramic)

(2) Output Voltage vs. Input Voltage

XC6223x121

Ta = 25℃
$C_{IN} = 1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)

XC6223x121

Ta = 25℃
$C_{IN} = 1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)

XC6223x181

Ta = 25℃
$C_{IN} = 1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)

XC6223x181

Ta = 25℃
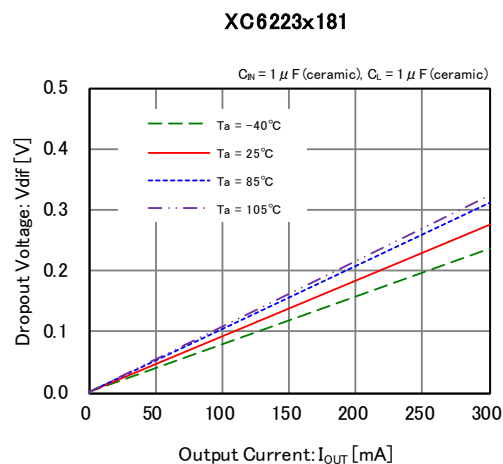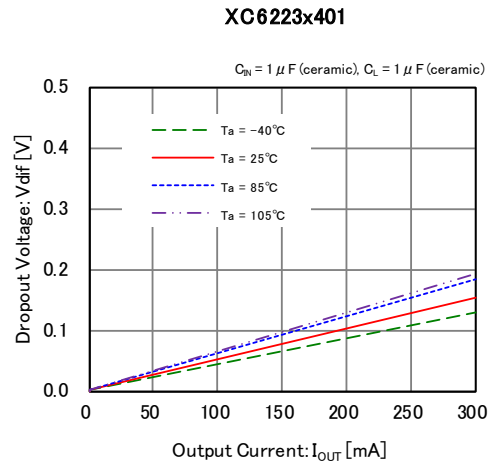$C_{IN} = 1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)

■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(2) Output Voltage vs. Input Voltage (Continued)

XC6223x251

Ta = 25℃
C_{IN} = 1 μF (ceramic), C_L = 1 μF (ceramic)

XC6223x251

Ta = 25℃
C_{IN} = 1 μF (ceramic), C_L = 1 μF (ceramic)

XC6223x401

Ta = 25℃
C_{IN} = 1 μF (ceramic), C_L = 1 μF (ceramic)
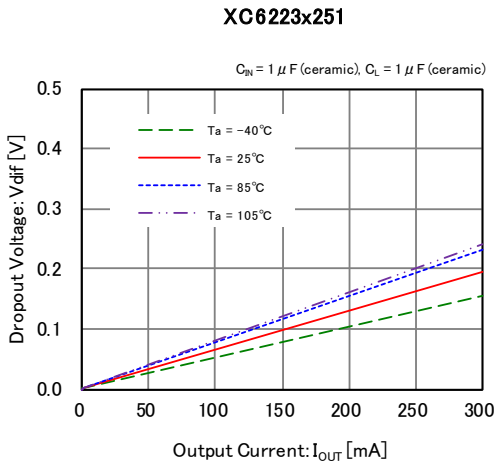

XC6223x401

Ta = 25℃
C_{IN} = 1 μF (ceramic), C_L = 1 μF (ceramic)

(3) Dropout Voltage vs. Output Current

XC6223x121

C_{IN} = 1 μF (ceramic), C_L = 1 μF (ceramic)

XC6223x181
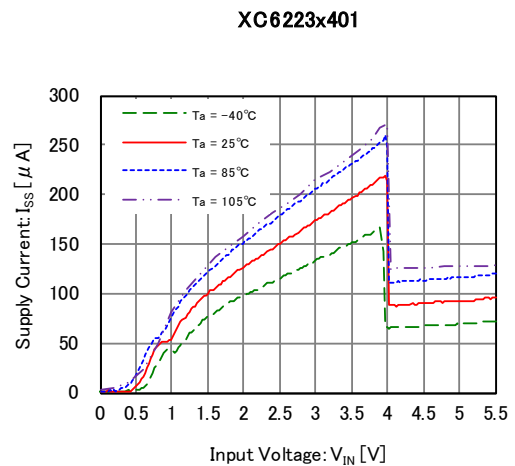
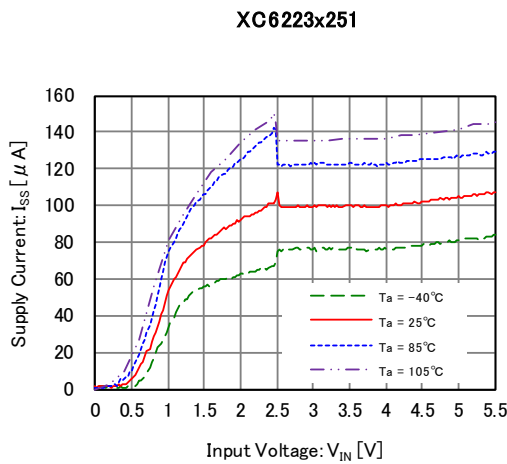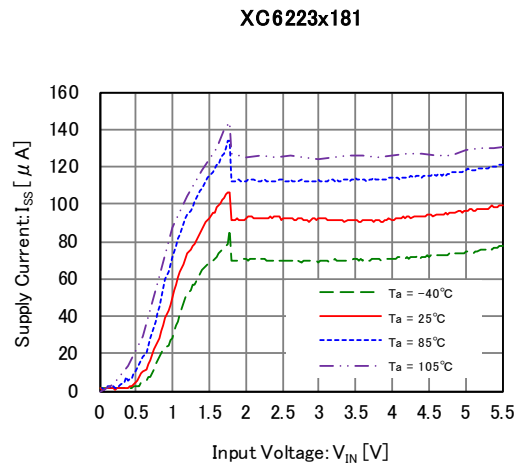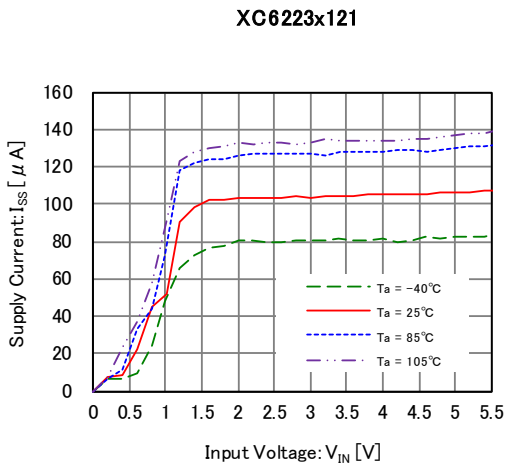C_{IN} = 1 μF (ceramic), C_L = 1 μF (ceramic)
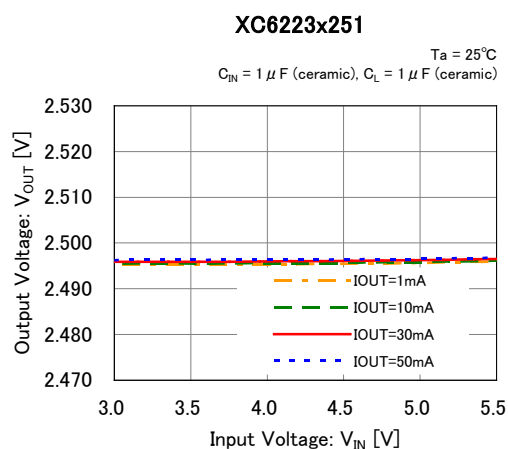
■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(3) Dropout Voltage vs. Output Current (Continued)

XC6223x251

$C_{IN} = 1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)
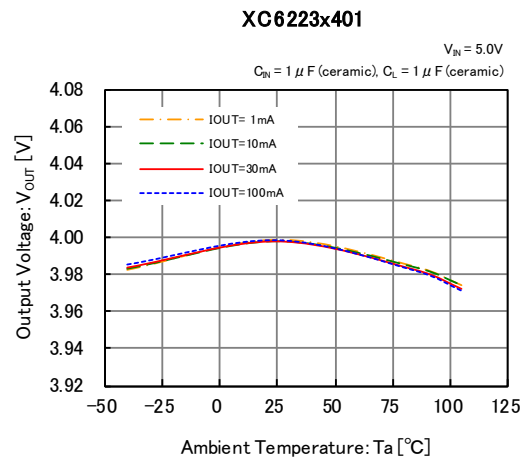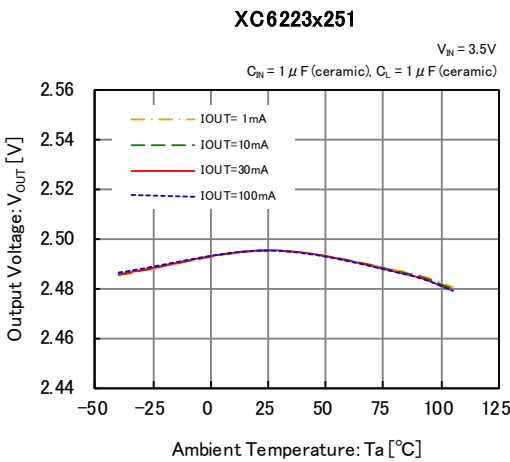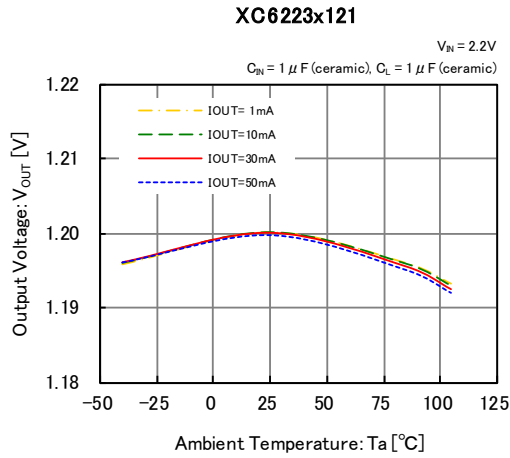

XC6223x401

$C_{IN} = 1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)

(4) Supply Current vs. Input Voltage

XC6223x121

XC6223x181

XC6223x251

XC6223x401

■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(5) Output Voltage vs. Ambient Temperature

XC6223x121

V_{IN} = 2.2V
C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

Output Voltage: V_{OUT} [V]
Ambient Temperature: Ta [℃]

- IOUT= 1mA
- IOUT=10mA
- IOUT=30mA
- IOUT=50mA

XC6223x181

V_{IN} = 2.8V
C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

Output Voltage: V_{OUT} [V]
Ambient Temperature: Ta [℃]

- IOUT= 1mA
- IOUT=10mA
- IOUT=30mA
- IOUT=100mA

XC6223x251

V_{IN} = 3.5V
C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

Output Voltage: V_{OUT} [V]
Ambient Temperature: Ta [℃]

- IOUT= 1mA
- IOUT=10mA
- IOUT=30mA
- IOUT=100mA

XC6223x401

V_{IN} = 5.0V
C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

Output Voltage: V_{OUT} [V]
Ambient Temperature: Ta [℃]

- IOUT= 1mA
- IOUT=10mA
- IOUT=30mA
- IOUT=100mA

(6) Rising Response Time

XC6223x121

tr = 5 μ s, Ta = 25℃,VIN = 0→2.2V
C_{IN} = 0.1 μ F (ceramic), C_L = 1 μ F (ceramic)

Input Voltage: V_{IN} [V]
Output Voltage: VOUT [V]
Time [50 μ s/div]

Input Voltage
Output Voltage

- IOUT=0.1mA
- IOUT=30mA
- IOUT=100mA

XC6223x181

tr = 5 μ s, Ta = 25℃,VIN = 0→2.8V
C_{IN} = 0.1 μ F (ceramic), C_L = 1 μ F (ceramic)

Input Voltage: V_{IN} [V]
Output Voltage: VOUT [V]
Time [50 μ s/div]

Input Voltage
Output Voltage

- IOUT=0.1mA
- IOUT=30mA
- IOUT=100mA

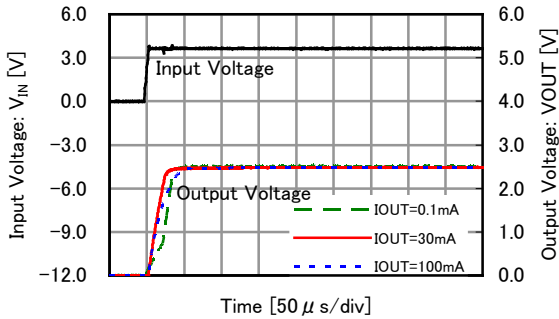## ■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(6) Rising Response Time (Continued)

XC6223x251

tr = 5 μs, Ta = 25℃, VIN = 0→3.5V
CIN = 0.1 μF (ceramic), C_L = 1 μF (ceramic)

XC6223x401

tr = 5 μs, Ta = 25℃, VIN = 0→5.0V
C_{IN} = 0.1 μF (ceramic), C_L = 1 μF (ceramic)
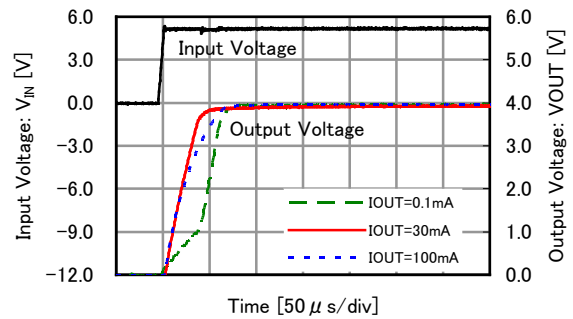
(7) Input Transient Response

XC6223x121

tr = tf = 5 μs, Ta = 25℃, VIN = 2.2V⇔3.2V
C_{IN} = 0.1 μF (ceramic), CL = 1.0 μF (ceramic)

XC6223x181

tr = tf = 5 μs, Ta = 25℃, VIN = 2.8V⇔3.8V
C_{IN} = 0.1 μF (ceramic), CL = 1.0 μF (ceramic)

XC6223x251

tr = tf = 5 μs, Ta = 25℃, VIN = 3.5V⇔4.5V
C_{IN} = 0.1 μF (ceramic), CL = 1.0 μF (ceramic)

XC6223x401

tr = tf = 5 μs, Ta = 25℃, VIN = 4.5V⇔5.5V
C_{IN} = 0.1 μF (ceramic), CL = 1.0 μF (ceramic)

■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(8) Load Transient Response (tr=tf=0.5μs)

XC6223x121
tr = tf = 0.5 μ s, Ta = 25℃, I$_{OUT}$ = 1⇔150mA
V$_{IN}$ = 2.2V, C$_{IN}$ = 1 μ F (ceramic), C$_L$ = 1 μ F (ceramic)

XC6223x121
tr = tf = 0.5 μ s, Ta = 25℃, I$_{OUT}$ = 50⇔100mA
V$_{IN}$ = 2.2V, C$_{IN}$ = 1 μ F (ceramic), C$_L$ = 1 μ F (ceramic)

XC6223x181
tr = tf = 0.5 μ s, Ta = 25℃, I$_{OUT}$ = 1⇔150mA
V$_{IN}$ = 2.8V, C$_{IN}$ = 1 μ F (ceramic), C$_L$ = 1 μ F (ceramic)

XC6223x181
tr = tf = 0.5 μ s, Ta = 25℃, I$_{OUT}$ = 50⇔100mA
V$_{IN}$ = 2.8V, C$_{IN}$ = 1 μ F (ceramic), C$_L$ = 1 μ F (ceramic)

XC6223x251
tr = tf = 0.5 μ s, Ta = 25℃, I$_{OUT}$ = 1⇔150mA
V$_{IN}$ = 3.5V, C$_{IN}$ = 1 μ F (ceramic), C$_L$ = 1 μ F (ceramic)

XC6223x251
tr = tf = 0.5 μ s, Ta = 25℃, I$_{OUT}$ = 50⇔100mA
V$_{IN}$ = 3.5V, C$_{IN}$ = 1 μ F (ceramic), C$_L$ = 1 μ F (ceramic)

■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(8) Load Transient Response (tr=tf=0.5μs) (Continued)

XC6223x401

tr = tf = 0.5 μ s, Ta = 25℃, I_{OUT} = 1⇔150mA
V_{IN} = 5.0V, C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

XC6223x401

tr = tf = 0.5 μ s, Ta = 25℃, I_{OUT} =50⇔100mA
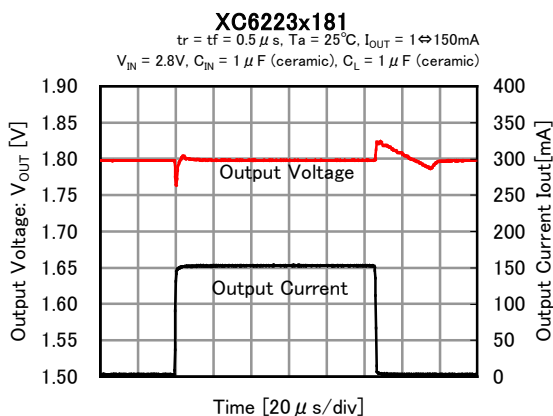V_{IN} = 5.0V, C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

(8) Load Transient Response (tr=tf=5μs) (Continued)

XC6223x121

tr = tf = 5 μ s, Ta = 25℃, I_{OUT} = 1⇔150mA
V_{IN} = 2.2V, C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

XC6223x121

tr = tf = 5 μ s, Ta = 25℃, I_{OUT} = 50⇔100mA
V_{IN} = 2.2V, C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

XC6223x181

tr = tf = 5 μ s, Ta = 25℃, I_{OUT} = 1⇔150mA
V_{IN} = 2.8V, C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

XC6223x181

tr = tf = 5 μ s, Ta = 25℃, I_{OUT} = 50⇔100mA
V_{IN} = 2.8V, C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

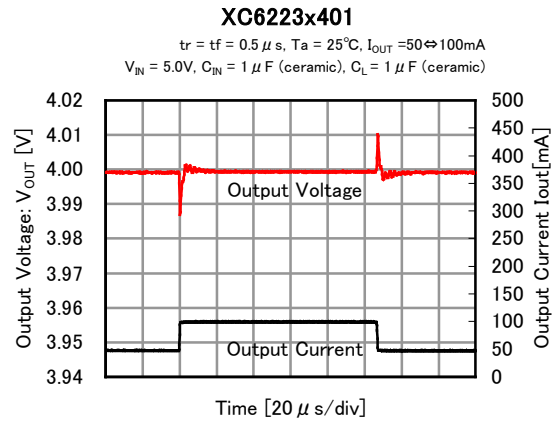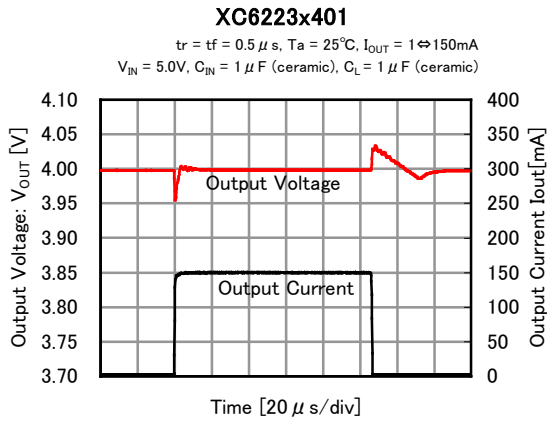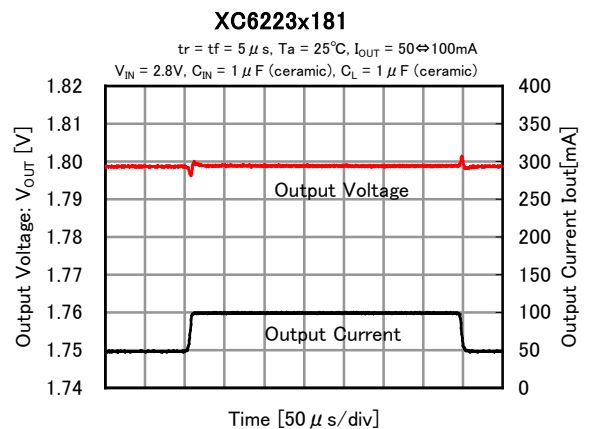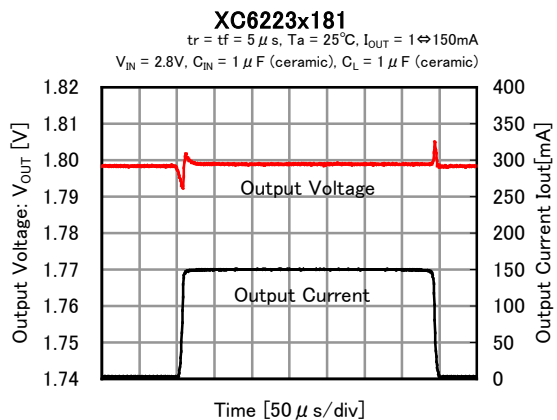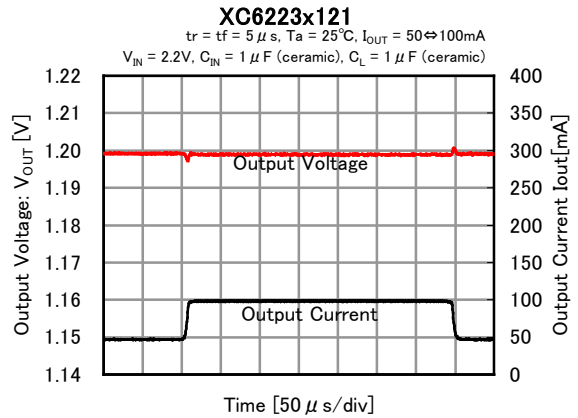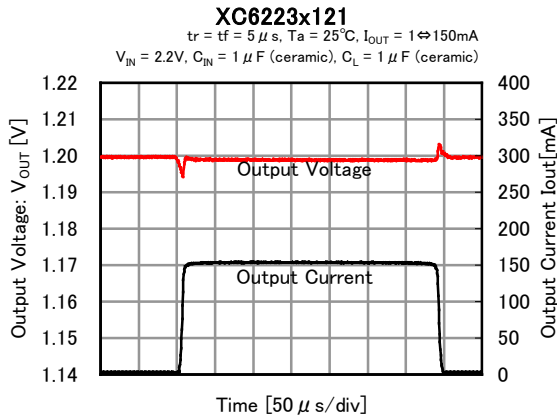# ■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)
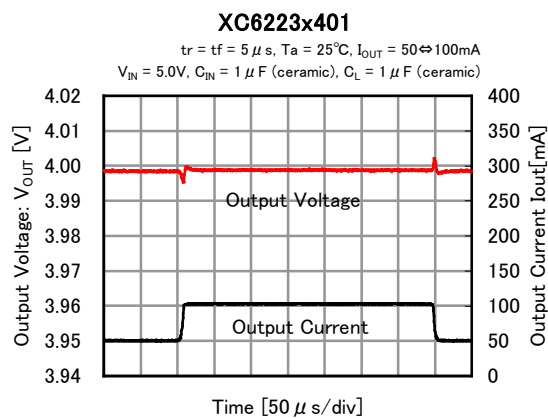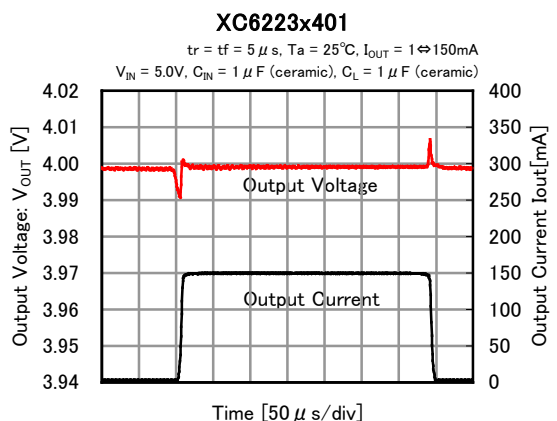
(8) Load Transient Response (tr=tf=5μs) (Continued)

XC6223x251
tr = tf = 5 μ s, Ta = 25℃, I_{OUT} = 1⇔150mA
V_{IN} = 3.5V, C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

XC6223x251
tr = tf = 5 μ s, Ta = 25℃, I_{OUT} = 50⇔100mA
V_{IN} = 3.5V, C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

XC6223x401
tr = tf = 5 μ s, Ta = 25℃, I_{OUT} = 1⇔150mA
V_{IN} = 5.0V, C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

XC6223x401
tr = tf = 5 μ s, Ta = 25℃, I_{OUT} = 50⇔100mA
V_{IN} = 5.0V, C_{IN} = 1 μ F (ceramic), C_L = 1 μ F (ceramic)

(9) CE Rising Response Time (A,B,C,D J,K,M,N Type)

XC6223x121
V_{IN} = 2.2V, tr = 5 μ s, Ta = 25℃
V_{CE} = 0→V_{IN}, C_{IN} = C_L = 1.0 μ F (ceramic)

XC6223x181
V_{IN} = 2.8V, tr = 5 μ s, Ta = 25℃
V_{CE} = 0→V_{IN}, C_{IN} = C_L = 1.0 μ F (ceramic)

■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(9) CE Rising Response Time (A,B,C,D,J,K,M,N Type) (Continued)

XC6223x251
V_{IN} = 3.5V, tr = 5μs, Ta = 25℃
V_{CE} = 0→V_{IN}, C_{IN} = C_L = 1.0μF (ceramic)

XC6223x401
V_{IN} = 5.0V, tr = 5μs, Ta = 25℃
V_{CE} = 0→V_{IN}, C_{IN} = C_L = 1.0μF (ceramic)
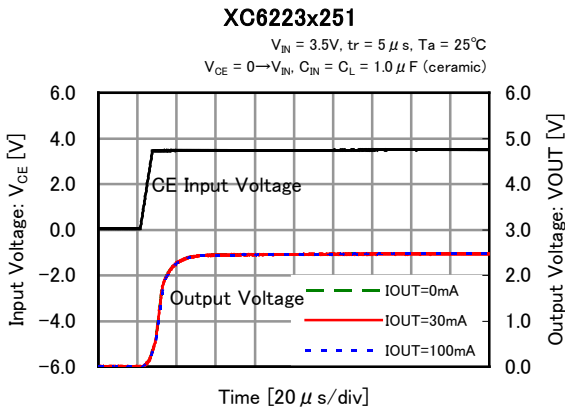
(9) CE Rising Response Time (E,F,G,H,P,Q,R,T Type) (Continued)

XC6223x121
V_{IN} = 2.2V, tr = 5μs, Ta = 25℃
V_{CE} = 0→V_{IN}, C_{IN} = C_L = 1.0μF (ceramic)

XC6223x181
V_{IN} = 2.8V, tr = 5μs, Ta = 25℃
V_{CE} = 0→V_{IN}, C_{IN} = C_L = 1.0μF (ceramic)

XC6223x251
V_{IN} = 3.5V, tr = 5μs, Ta = 25℃
V_{CE} = 0→V_{IN}, C_{IN} = C_L = 1.0μF (ceramic)

XC6223x401
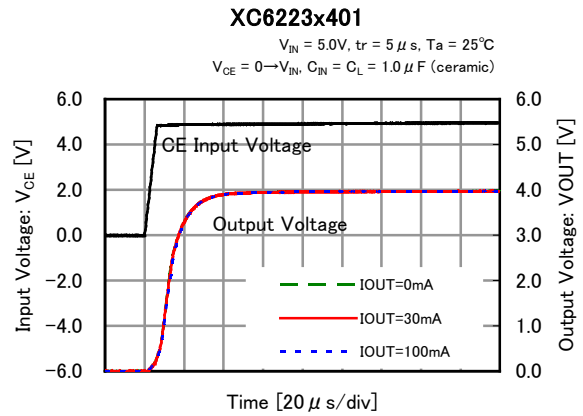V_{IN} = 5.0V, tr = 5μs, Ta = 25℃
V_{CE} = 0→V_{IN}, C_{IN} = C_L = 1.0μF (ceramic)
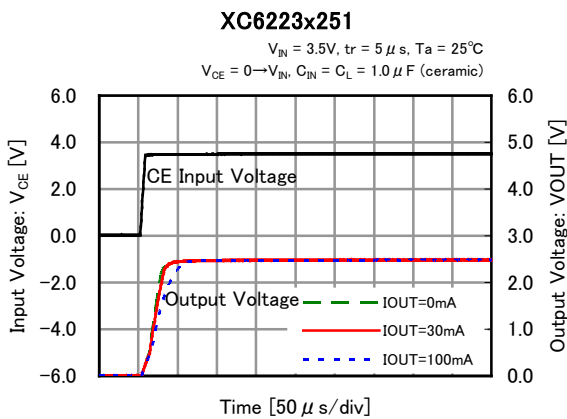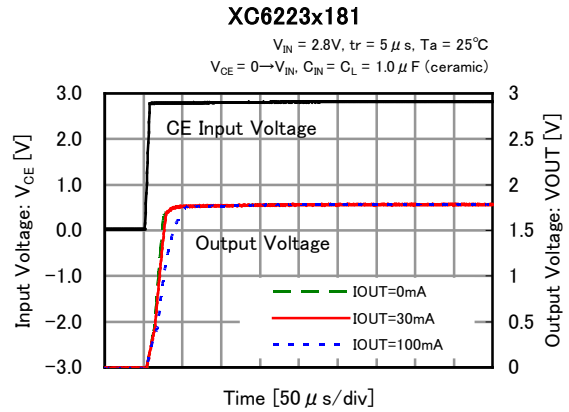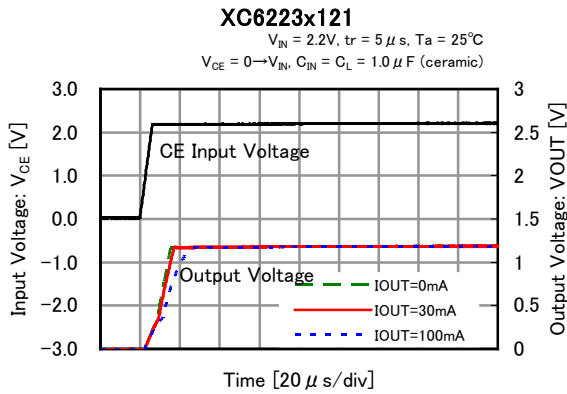
■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(10) Inrush Current Response Time (E,F,G,H,P,Q,R,T Type)

XC6223x121
V_{IN} = 2.2V, tr = 5 μ s, Ta = 25℃
V_{CE} = 0→V_{IN}, C_{IN} = C_L = 1.0 μ F (ceramic)

XC6223x181
V_{IN} = 2.8V, tr = 5 μ s, Ta = 25℃
V_{CE} = 0→V_{IN}, C_{IN} = C_L = 1.0 μ F (ceramic)

XC6223x251
V_{IN} = 3.5V, tr = 5 μ s, Ta = 25℃
V_{CE} = 0→V_{IN}, C_{IN} = C_L = 1.0 μ F (ceramic)

XC6223x401
V_{IN} = 5.0V, tr = 5 μ s, Ta = 25℃
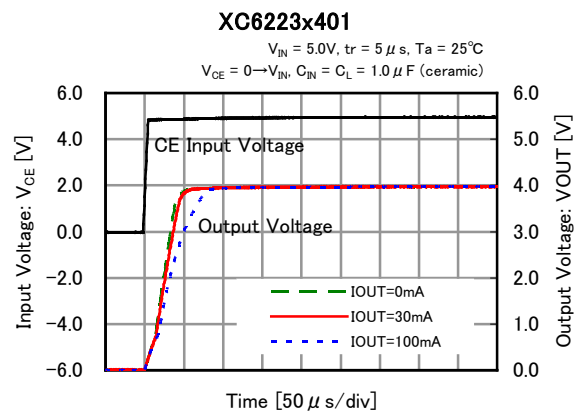V_{CE} = 0→V_{IN}, C_{IN} = C_L = 1.0 μ F (ceramic)
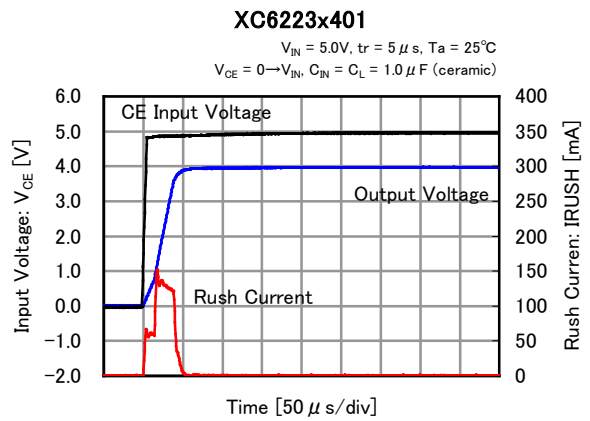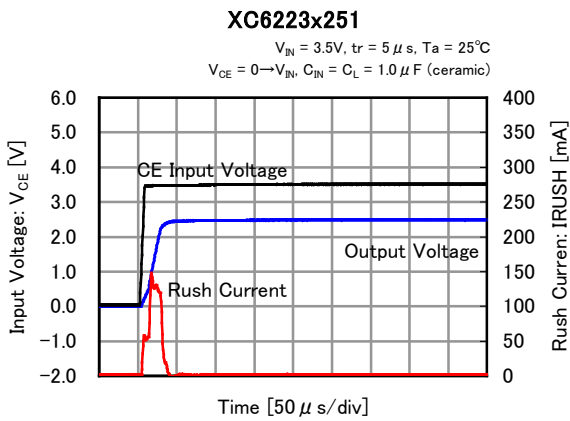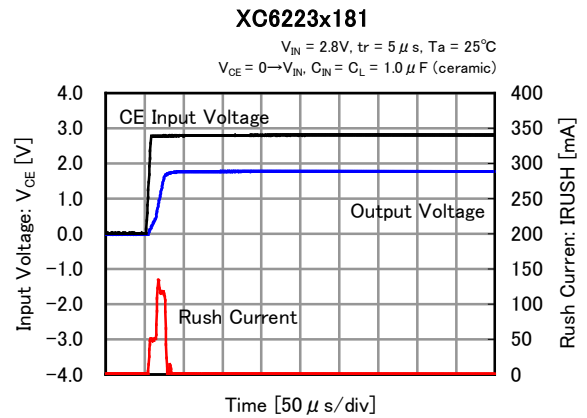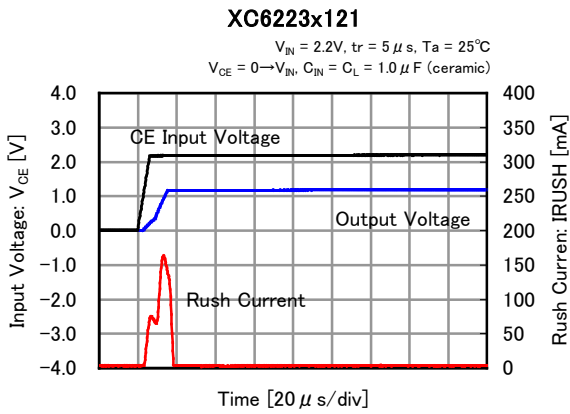
■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(11) Ripple Rejection Rate

XC6223x121

Ta = 25℃, V_{IN} = 3.0VDC+0.5Vp–pAC
C_{IN} = 0.1μF (ceramic), C_L = 1μF (ceramic)
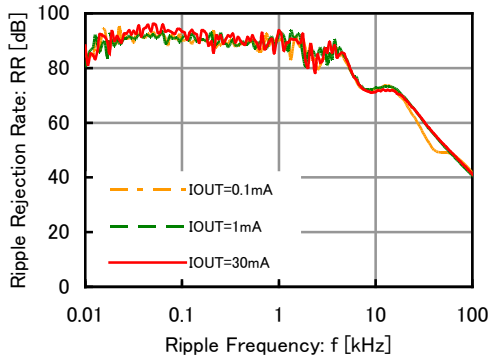
XC6223x181

Ta = 25℃, V_{IN} = 3.0VDC+0.5Vp–pAC
C_{IN} = 0.1μF (ceramic), C_L = 1μF (ceramic)
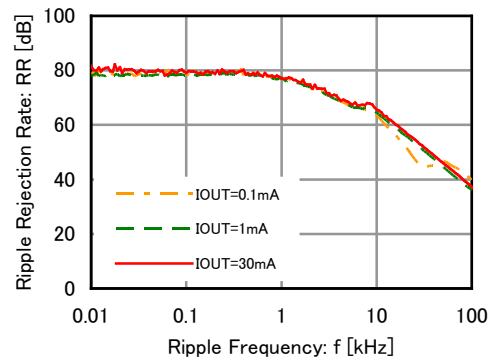
XC6223x251

Ta = 25℃, V_{IN} = 3.5VDC+0.5Vp–pAC
C_{IN} = 0.1μF (ceramic), C_L = 1μF (ceramic)
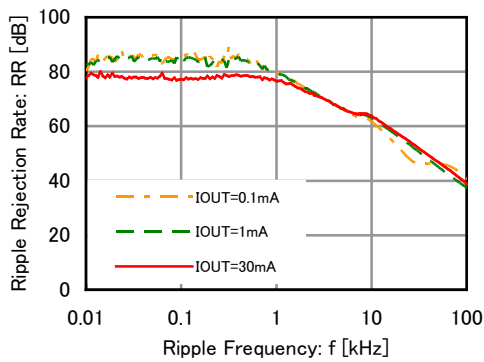
XC6223x331

Ta = 25℃, V_{IN} = 4.3VDC+0.5Vp–pAC
C_{IN} = 0.1μF (ceramic), C_L = 1μF (ceramic)
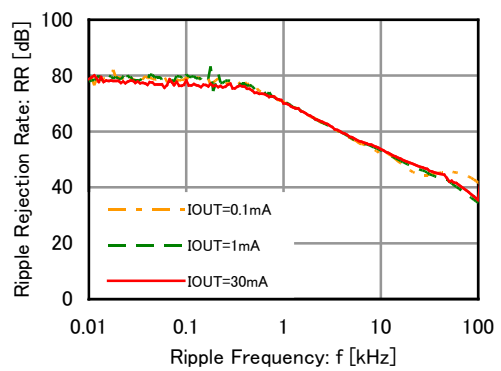
■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(12) Output Noise Density

XC6223x121

V_{IN}=2.2V, Ta=25℃
C_{IN}=C_L=1.0μF(ceramic)

Frequency−Range : 0.1〜100kHz
Output Noise : 32.60μVrms

IOUT=30mA

Output Noise Density : [μV/$\sqrt{}$Hz]

Frequency : f [kHz]

XC6223x181

V_{IN}=2.8, Ta=25℃
C_{IN}=C_L=1.0μF(ceramic)

Frequency−Range : 0.1〜100kHz
Output Noise : 49.74μVrms

IOUT=30mA

Output Noise Density : [μV/$\sqrt{}$Hz]

Frequency : f [kHz]

XC6223x331

V_{IN}=5.0V, Ta=25℃
C_{IN}=C_L=1.0μF(ceramic)

Frequency−Range : 0.1〜100kHz
Output Noise : 81.52μVrms

IOUT=30mA

Output Noise Density : [μV/$\sqrt{}$Hz]

Frequency : f [kHz]

XC6223 Series

■PACKAGING INFORMATION

For the latest package information go to, www.torexsemi.com/technical-support/packages

PACKAGE	OUTLINE / LAND PATTERN	THERMAL CHARACTERISTICS	
USPQ-4B03	USPQ-4B03 PKG	Standard Board	USPQ-4B03 Power Dissipation
USP-4	USP-4 PKG	Standard Board	USP-4 Power Dissipation
SSOT-24	SSOT-24 PKG	Standard Board	SSOT-24 Power Dissipation
		JESD51-7 Board	
SOT-25	SOT-25 PKG	Standard Board	SOT-25 Power Dissipation
		JESD51-7 Board	
SOT-89-5	SOT-89-5 PKG	Standard Board	SOT-89-5 Power Dissipation
		JESD51-7 Board	

■MARKING RULE
●USPQ-4B03

① represents type of regulator and output voltage range.

MARK			PRODUCT SERIES
OUTPUT VOLTAGE 0.1V INCREMENTS		OUTPUT VOLTAGE 0.05V INCREMENTS	
VOLTAGE=1.2～3.9V	VOLTAGE =4.0V	VOLTAGE =1.25～3.95V	
0		8	XC6223A/J*****
1		9	XC6223B/K*****
2		A	XC6223C/M*****
3		B	XC6223D/N*****
4	H	C	XC6223E/P*****
5		D	XC6223F/Q*****
6		E	XC6223G/R*****
7		F	XC6223H/T*****

```
   4        3
   ┌──────────┐
   │ ① │ ② │
   │○  ③ │ ④ │
   └──────────┘
   1        2

USPQ-4B03
(TOP VIEW)
```
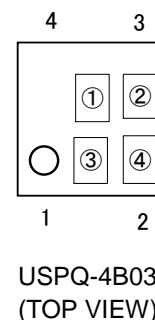
② represents output voltage.

VOLTAGE=1.2～3.95[V]

MARK	OUTPUT VOLTAGE（V）		MARK	OUTPUT VOLTAGE（V）	
0	-	-	F	2.50	2.55
1	-	-	H	2.60	2.65
2	1.20	1.25	K	2.70	2.75
3	1.30	1.35	L	2.80	2.85
4	1.40	1.45	M	2.90	2.95
5	1.50	1.55	N	3.00	3.05
6	1.60	1.65	P	3.10	3.15
7	1.70	1.75	R	3.20	3.25
8	1.80	1.85	S	3.30	3.35
9	1.90	1.95	T	3.40	3.45
A	2.00	2.05	U	3.50	3.55
B	2.10	2.15	V	3.60	3.65
C	2.20	2.25	X	3.70	3.75
D	2.30	2.35	Y	3.80	3.85
E	2.40	2.45	Z	3.90	3.95

VOLTAGE=4.0[V]

PRODUCT SERIES	MARK
XC6223A/J*****	0
XC6223B/K*****	1
XC6223C/M*****	2
XC6223D/N*****	3
XC6223E/P*****	4
XC6223F/Q*****	5
XC6223G/R*****	6
XC6223H/T*****	7

③④ represents production lot number.
01 to 09, 0A to 0Z, 11 to 9Z, A1 to A9, AA to Z9, ZA to ZZ in order.
 (G, I, J, O, Q, W excepted)
*No character inversion used.

■MARKING RULE (Continued)

●SSOT-24 (with bar)

① represents type of regulator and output voltage range.

MARK			PRODUCT SERIES
OUTPUT VOLTAGE 0.1V INCREMENTS		OUTPUT VOLTAGE 0.05V INCREMENTS	
VOLTAGE =1.2～2.9V	VOLTAGE =3.0 ～4.0V	VOLTAGE =1.25～3.95V	
B	3	8	XC6223A/J*****
C	5	9	XC6223B/K*****
D	7	S	XC6223C/M*****
E	A	T	XC6223D/N*****
K	F	U	XC6223E/P*****
L	H	V	XC6223F/Q*****
M	P	X	XC6223G/R*****
N	Z	Y	XC6223H/T*****
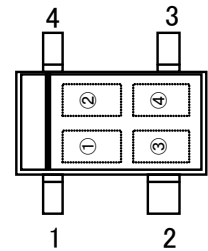
SSOT-24(with bar)
(TOP VIEW)

② represents output voltage.

MARK	OUTPUT VOLTAGE (V)				MARK	OUTPUT VOLTAGE (V)			
0	-	-	-	-	F	2.50	3.20	-	2.55
1	-	-	-	-	H	2.60	3.30	-	2.65
2	1.20	-	-	1.25	K	2.70	3.40	-	2.75
3	1.30	-	-	1.35	L	2.80	3.50	-	2.85
4	1.40	-	-	1.45	M	2.90	3.60	-	2.95
5	1.50	-	-	1.55	N	-	-	-	3.05
6	1.60	-	-	1.65	P	-	3.70	-	3.15
7	1.70	-	-	1.75	R	-	3.80	-	3.25
8	1.80	-	-	1.85	S	-	3.90	-	3.35
9	1.90	-	-	1.95	T	-	4.00	-	3.45
A	2.00	-	-	2.05	U	-	-	-	3.55
B	2.10	-	-	2.15	V	-	-	-	3.65
C	2.20	-	-	2.25	X	-	-	-	3.75
D	2.30	3.00	-	2.35	Y	-	-	-	3.85
E	2.40	3.10	-	2.45	Z	-	-	-	3.95

③④ represents production lot number.
01 to 09, 0A to 0Z, 11 to 9Z, A1 to A9, AA to Z9, ZA to ZZ in order.
  (G, I, J, O, Q, W excepted)
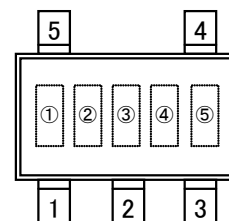*No character inversion used.

■MARKING RULE (Continued)
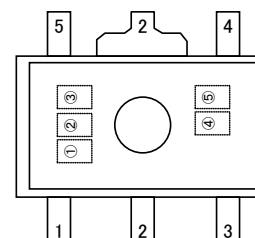
●SOT-25, SOT-89-5,USP-4
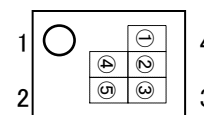
① represents product series

MARK	PRODUCT SERIES
9	XC6223******

② represents type of regulator.

MARK			PRODUCT SERIES
OUTPUT VOLTAGE 0.1V INCREMENTS		OUTPUT VOLTAGE 0.05V INCREMENTS	
VOLTAGE =1.2～3.9V	VOLTAGE =4.0V	VOLTAGE =1.25～3.95V	
C	D	E	XC6223A/J*****
F	H	K	XC6223B/K*****
L	M	N	XC6223C/M*****
P	R	S	XC6223D/N*****
T	U	V	XC6223E/P*****
X	Y	Z	XC6223F/Q*****
0	1	2	XC6223G/R*****
3	4	5	XC6223H/T*****

③ represents output voltage.

MARK	OUTPUT VOLTAGE (V)				MARK	OUTPUT VOLTAGE (V)			
0	-	4.00	-		F	2.50	-	2.55	-
1	-	-	-		H	2.60	-	2.65	-
2	1.20	-	1.25	-	K	2.70	-	2.75	-
3	1.30	-	1.35	-	L	2.80	-	2.85	-
4	1.40	-	1.45	-	M	2.90	-	2.95	-
5	1.50	-	1.55	-	N	3.00	-	3.05	-
6	1.60	-	1.65	-	P	3.10	-	3.15	-
7	1.70	-	1.75	-	R	3.20	-	3.25	-
8	1.80	-	1.85	-	S	3.30	-	3.35	-
9	1.90	-	1.95	-	T	3.40	-	3.45	-
A	2.00	-	2.05	-	U	3.50	-	3.55	-
B	2.10	-	2.15	-	V	3.60	-	3.65	-
C	2.20	-	2.25	-	X	3.70	-	3.75	-
D	2.30	-	2.35	-	Y	3.80	-	3.85	-
E	2.40	-	2.45	-	Z	3.90	-	3.95	-

④⑤ represents production lot number.

01 to 09, 0A to 0Z, 11 to 9Z, A1 to A9, AA to Z9, ZA to ZZ in order.

(G, I, J, O, Q, W excepted)

*No character inversion used.

SOT-25 (TOP VIEW)

SOT-89-5 (TOP VIEW)

USP-4 (TOP VIEW)

1. The product and product specifications contained herein are subject to change without notice to improve performance characteristics. Consult us, or our representatives before use, to confirm that the information in this datasheet is up to date.

2. The information in this datasheet is intended to illustrate the operation and characteristics of our products. We neither make warranties or representations with respect to the accuracy or completeness of the information contained in this datasheet nor grant any license to any intellectual property rights of ours or any third party concerning with the information in this datasheet.

3. Applicable export control laws and regulations should be complied and the procedures required by such laws and regulations should also be followed, when the product or any information contained in this datasheet is exported.

4. The product is neither intended nor warranted for use in equipment of systems which require extremely high levels of quality and/or reliability and/or a malfunction or failure which may cause loss of human life, bodily injury, serious property damage including but not limited to devices or equipment used in 1) nuclear facilities, 2) aerospace industry, 3) medical facilities, 4) automobile industry and other transportation industry and 5) safety devices and safety equipment to control combustions and explosions. Do not use the product for the above use unless agreed by us in writing in advance.

5. Although we make continuous efforts to improve the quality and reliability of our products; nevertheless Semiconductors are likely to fail with a certain probability. So in order to prevent personal injury and/or property damage resulting from such failure, customers are required to incorporate adequate safety measures in their designs, such as system fail safes, redundancy and fire prevention features.

6. Our products are not designed to be Radiation-resistant.

7. Please use the product listed in this datasheet within the specified ranges.

8. We assume no responsibility for damage or loss due to abnormal use.

TOREX SEMICONDUCTOR LTD.